

SML75SUZ12L

Ultrafast Recovery Diode 1200 Volt, 75Amp

Back of Case Cathode SML 75SUZ12L 1 - Cathode 2 - Anode 1 2

See Package outline for mechanical data and more details

TO-264

Key Parameters

V _R (max)	1200V		
V _F (typ)	2.1V		
I _F (max)	75A		
t _{rr} (max)	75ns		

TECHNOLOGY

The planar passivated and standard ultrafast recovery diode features a triple charge control action utilising Semelab's Graded Buffer Zone technology combined with low emitter efficiency and local lifetime control techniques.

BENEFITS

- · Very fast recovery for low switching losses
- Ultra soft recovery with low EMI generation
- High dynamic ruggedness under all conditions
- · Low temperature dependency
- Low on-state losses with positive temperature coefficient
- · Stable blocking voltage and low leakage current
- Avalanche rated for high reliability circuit operation

APPLICATIONS

- Freewheeling Diode for IGBTs and MOSFETs
- Uninterruptible Power Supplies UPS
- Switch Mode Power Supplies SMPS
- · Inverse and Clamping Diode
- Snubber Diode
- · Fast Switching Rectification

ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C unless otherwise stated)

$\overline{V_{RRM}}$	Peak Repetitive Reverse Voltage	1200V		
V_R	DC Reverse Blocking Voltage	1200V		
I_{FAV}	Average Forward Current @T _C = 85°C	75A		
I _{FSM(surge)}	Repetitive Forward Current	175A		
I _{FS(surge)}	Non-Repetitive Forward Current	750A		
P_{D}	Power Dissipation @T _C = 85°C	170W		
W_{AVL}	Avalanche Energy	50mJ		
T_J , T_STG	Operating & Storage Junction Temperature	-55 to 150°C		

Semelab PIc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

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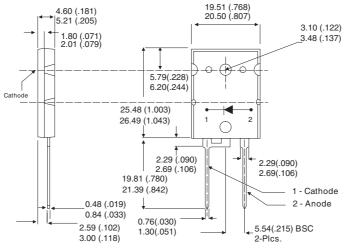


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ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

	Parameter	Test Cor	nditions	Min.	Тур.	Max.	Unit
STATIC	ELECTRICAL CHARACTERISTIC			•			
		I _F = 75A	T _j = 25°C		2.1	2.75	
V _F Forward Voltage Drop	I _F = 75A	T _j = 125°C			2.8	V	
		I _F = 50A	T _j = 25°C		1.85		
I _R Leakage Current	Lookaga Current	V _R = 1200V	T _j = 25°C		2	1000	μΑ
	Leakage Current	V _R = 1200V	T _j = 125°C		2	7.5	mA
C _T	Junction Capacitance	V _R = 200V	T _j = 25°C		84		pF
DYNAMI	C ELECTRICAL CHARACTERIS	TIC	-		'		
Q _{rr}	Reverse Recovery Charge	$V_{R} = 600V$ $d_{i} / d_{t} = 1000A/\mu s$			2.38		μC
I _{rr}	Reverse Recovery Current				50		Α
t _{rr}	Reverse Recovery Time		1 _J = 25 C		95		nsec
Q _{rr}	Reverse Recovery Charge	$V_R = 600V$ $d_i / d_t = 1000A/\mu s$	1 7EA		4.63		μC
I _{rr}	Reverse Recovery Current		-		75		Α
t _{rr}	Reverse Recovery Time		1 _J = 125 C		125		nsec
t _{rr} Reverse Recovery Tim	Davis Davis Davis Time	$V_R = 50V$	I _F = 1A		75		nsec
	Reverse Recovery Time	$d_i / d_t = 100A/\mu s$	$T_J = 25^{\circ}C$				
THERM	AL AND MECHANICAL CHARAC	TERISTICS					
$R_{\theta jc}$	Junction to Case Thermal Resistance				0.4	°C/W	
T _L	Lead Temperature					300	°C
L _S	Stray Inductance				10		nH
Torque	Mounting Torque					1.1	N.m

TO-264 Package Outline



Dimensions in Millimeters and (Inches)

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